

RB160M-30,40,60,90

Reverse Voltage - 30 to 90

Forward Current - 1.0 A

Surface Mount Schottky Barrier Rectifier FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



PIN DESCRIPTION 1: Cathode 2: Anode Simplified outline SOD-123FL and symbol

MECHANICAL DATA

• Case: SOD-123FL

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight:15mg 0.00048oz

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	RB160M-30	RB160M-40	RB160M-60	RB160M-90	Units		
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	30 40		60	90	٧		
Maximum RMS voltage	V _{RMS}	21 28		42	63	V		
Maximum DC Blocking Voltage	V _{DC}	30	40	60	90	V		
Maximum Average Forward Rectified Current	I _{F(AV)}	1.0						
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}		30	Α				
Max Instantaneous Forward Voltage at 1 A	V _F	0.0	0.55 0.70			V		
Maximum DC Reverse Current $T_a = 25^{\circ}$ C at Rated DC Reverse Voltage $T_a = 100^{\circ}$ C	IR		0.3 10		0.2 5	mA		
Typical Junction Capacitance 1)	Cj	110	80			pF		
Typical Thermal Resistance 2)	Reja	115						
Operating Junction Temperature Range	Tj	-55~+125						
Storage Temperature Range	T _{stg}	-55 ~ +150						

¹⁾ Measured at 1MHz and applied reverse voltage of 4 V D.C.

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²⁾ P.C.B. mounted with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



Fig.1 Forward Current Derating Curve

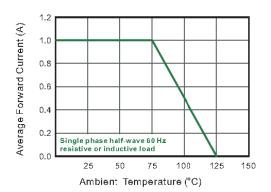


Fig.2 Typical Reverse Characteristics

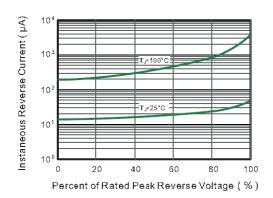


Fig.3 Typical Forward Characteristic

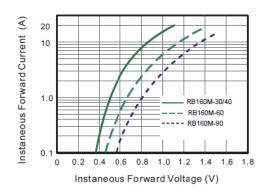


Fig.4 Typical Junction Capacitance

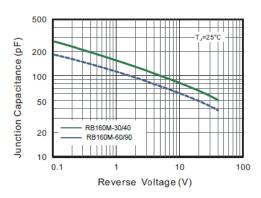


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

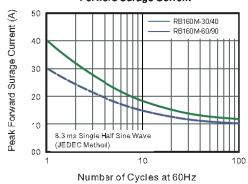
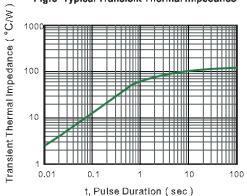


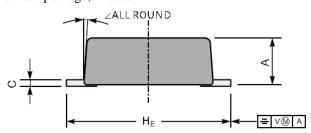
Fig.6- Typical Transient Thermal Impedance

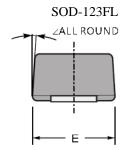


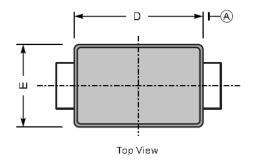
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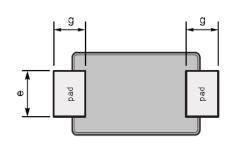
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads





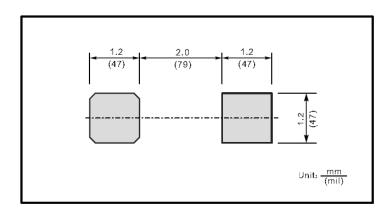




Bottom View

UNIT		Α	С	D	Е	е	g	HE	Z	
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8		
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	7°	
mil	max	43	7.9	114	75	43	35	150		
	min	35	4.7	102	67	31	28	138		

The recommended mounting pad size



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